NSN 5962-01-443-0935

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View Online at https://aerobasegroup.com/nsn/59
Maximum Power Dissipation Rating:
1.0 watts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
End Application:
1260-01-432-8524, control-display system
Features Provided:
Monolithic and 3-state output
Inclosure Material:
Ceramic
Inclosure Configuration:
Pin grid array
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Product Name:
Digital cmos 32k x 8 eeprom
Voltage Rating And Type Per Characteristic:
5.0 volts power source
Time Rating Per Chacteristic:
150.00 nanoseconds access
Memory Device Type:
Eeprom
Memory Capacity:
32, 768 word quantity and 256 bit quantity
Special Features:
Endurance: 10, 000cycles/byte (min)
Terminal Type And Quantity:
28 pin
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli

Fiig:

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